

RQK0605JGDQA

Silicon N Channel MOS FET Power Switching

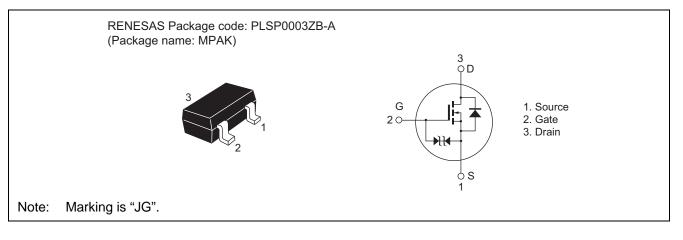
R07DS0309EJ0600 Rev.6.00 Jan 10, 2014

Datasheet

Features

- Low on-resistance
- $R_{DS(on)} = 82 \text{ m}\Omega \text{ typ } (V_{GS} = 10 \text{ V}, I_D = 1.5 \text{ A})$
- Low drive current
- High speed switching
- 4.5 V gate drive

Outline



Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	60	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	ID	3.1	А
Drain peak current	I _{D(Pulse)} Note1	4.5	А
Body - drain diode reverse drain current	I _{DR}	3.1	А
Channel dissipation	Pch ^{Note2}	0.8	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. $PW \le 10 \ \mu s$, duty cycle $\le 1\%$

2. When using the glass epoxy board (FR-4: $40 \times 40 \times 1$ mm)



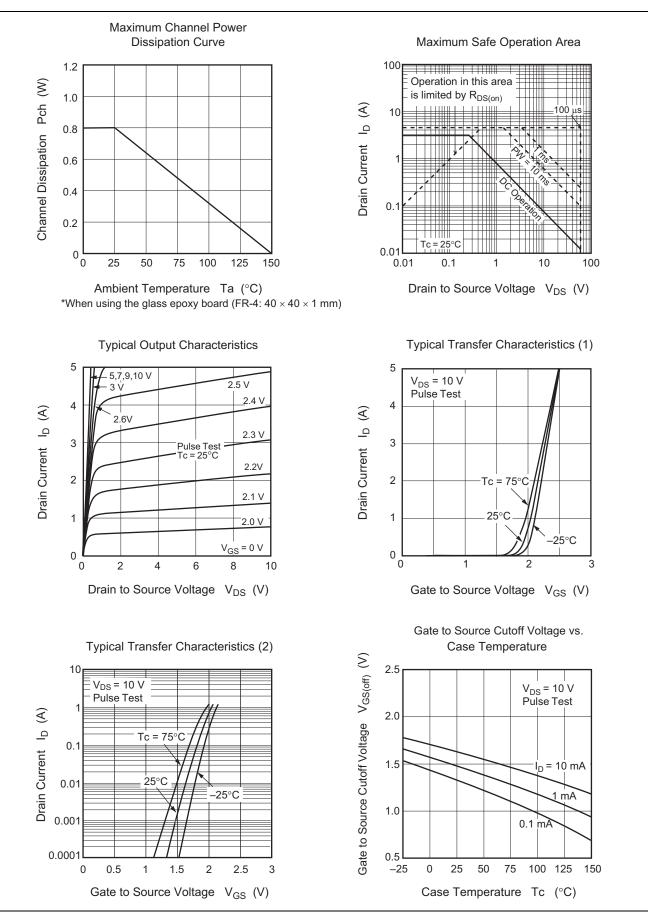
Electrical Characteristics

						$(Ta = 25^{\circ}C)$	
Item	Symbol	Min	Тур	Max	Unit	Test conditions	
Drain to source breakdown voltage	V _{(BR)DSS}	60	—		V	$I_D = 10 \text{ mA}, V_{GS} = 0$	
Gate to source breakdown voltage	V _{(BR)GSS}	±20	—		V	$I_G = \pm 100 \ \mu A, V_{DS} = 0$	
Gate to source leak current	I _{GSS}	_	—	±10	μA	$V_{GS}=\ \pm 16\ V,\ V_{DS}=0$	
Drain to source leak current	I _{DSS}	_	—	1	μA	$V_{DS} = 60 V, V_{GS} = 0$	
Gate to source cutoff voltage	V _{GS(off)}	1.0	—	2.0	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$	
Drain to source on state resistance	R _{DS(on)}	_	82	103	mΩ	$I_D = 1.5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note3}}$	
	R _{DS(on)}	_	93	131	mΩ	$I_D = 1.5 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note3}}$	
Forward transfer admittance	y _{fs}	3.6	6		S	$I_D = 1.5 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note3}}$	
Input capacitance	Ciss	_	405		pF	$V_{DS} = 10 V, V_{GS} = 0,$	
Output capacitance	Coss	_	58	_	pF	f = 1 MHz	
Reverse transfer capacitance	Crss	_	23		pF		
Turn - on delay time	t _{d(on)}	_	14	_	ns	$I_D = 1 \text{ A}, V_{GS} = 10 \text{ V},$	
Rise time	tr	_	43	_	ns	$R_L = 10 \Omega$, $Rg = 4.7 \Omega$	
Turn - off delay time	t _{d(off)}	_	43	_	ns		
Fall time	t _f	_	3.7	_	ns		
Total gate charge	Qg	_	6.9	_	nC	$V_{DD} = 10 \text{ V}, \text{ V}_{GS} = 10 \text{ V},$	
Gate to source charge	Qgs	_	0.9	_	nC	I _D = 3.1A	
Gate to drain charge	Qgd	_	0.8	_	nC	1	
Body - drain diode forward voltage	V _{DF}	—	0.8	—	V	$I_F = 1.5 \text{ A}, V_{GS} = 0^{Note3}$	

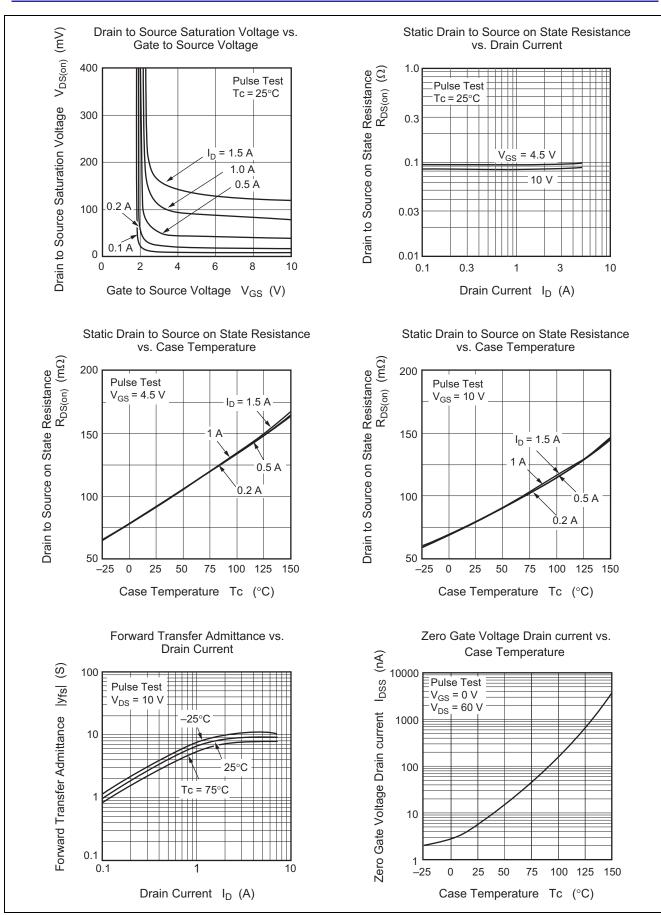
Notes: 3. Pulse test

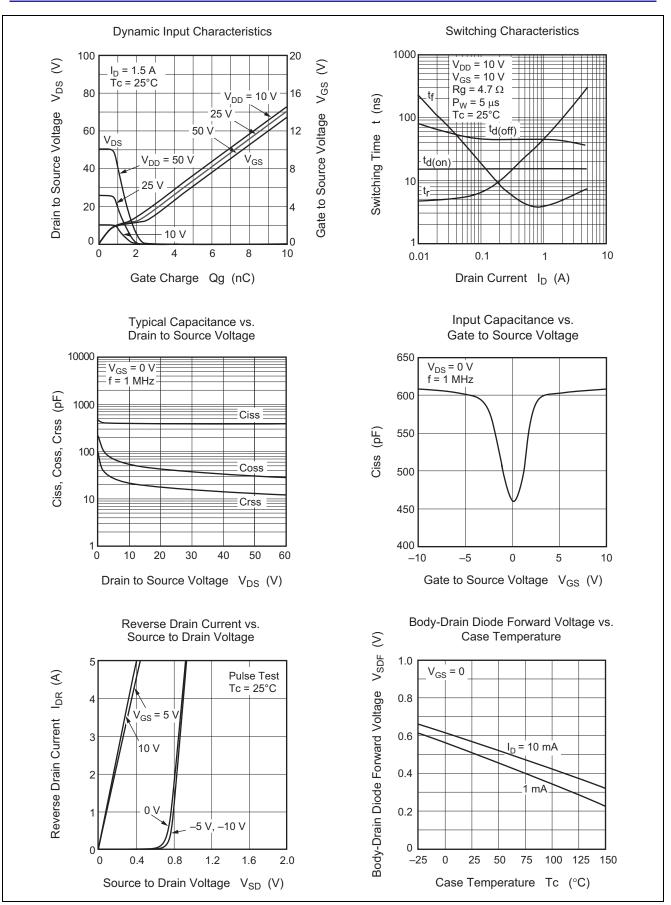


Main Characteristics



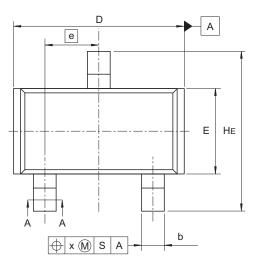


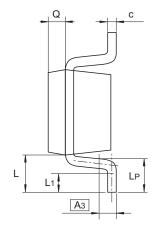


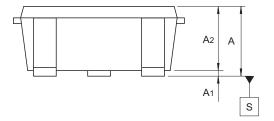


Package Dimensions

JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
SC-59A	PLSP0003ZB-A	MPAK(T) / MPAK(T)V	0.011











Reference	Dimensions in millimeters		
Symbol	Min	Nom	Max
A	1.0		1.3
A ₁	0		0.1
A ₂	1.0	1.1	1.2
A ₃		0.25	—
b	0.35	0.4	0.5
С	0.1	0.16	0.26
D	2.7		3.1
E	1.35	1.5	1.65
е		0.95	
HE	2.2	2.8	3.0
L	0.35	—	0.75
L ₁	0.15		0.55
Lp	0.25		0.65
Х			0.05
Q		0.3	

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Ordering Information

Orderable Part Number	Quantity	Shipping Container
RQK0605JGDQATL-H	3000 pcs.	φ178 mm reel, 8 mm Emboss taping



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